

Question:

A class-A emitter follower biased with a constant-current source is shown in **Figure 1**. Study **Figure 1** carefully. The transistor parameters are: $\beta = 180$, $V_{BE} = 0.7 \text{ V}$, and $V_{CE(\text{sat})} = 0.2 \text{ V}$. Neglecting base currents:

- (i) Find the value of I_Q . [3 marks]
- (ii) Determine the value of R that will produce the maximum possible output signal swing. [3 marks]
- (iii) Calculate the power conversion efficiency. Consider all power delivered to all transistors. [4 marks]

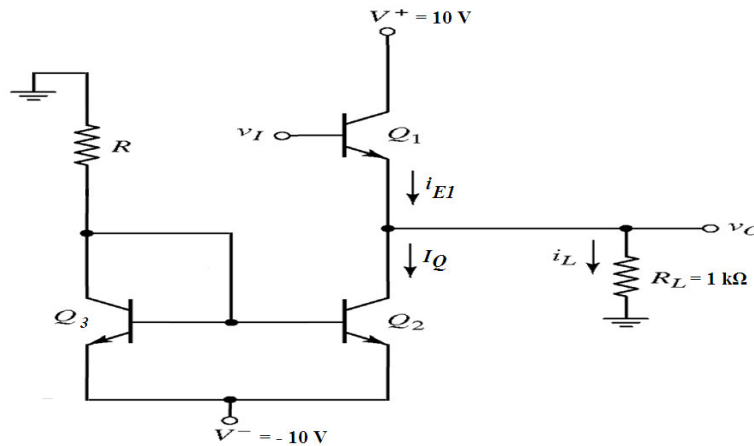


Figure 1

Answer: (You may continue writing your answer in the next page)

(i) $v_{O(\text{max})} = V^+ - V_{CE(\text{sat})} = 10 - 0.2 = 9.8 \text{ V}$
 $I_Q = i_{L(\text{max})} = v_{O(\text{max})} / R_L = 9.8 / 1\text{k} = 9.8 \text{ mA}$

(ii) $R = (0 - V_{BE} - (-10)) / I_Q = 9.3 / 9.8\text{m} = 949 \Omega$

(iii)
$$\bar{P}_L = \frac{1}{2} (i_{L(\text{max})})^2 R_L = \frac{1}{2} (9.8\text{m})^2 (1\text{k})$$

$$\Rightarrow \bar{P}_L = 48.02\text{mW}$$

$$\bar{P}_S = I_Q (V^+ - V^-) + I_Q (0 - V^-)$$

$$\Rightarrow \bar{P}_S = 9.8\text{m}(20) + 9.8\text{m}(10) = 294\text{mW}$$

$$\eta = \frac{\bar{P}_L}{\bar{P}_S} = \frac{48.02\text{m}}{294\text{m}} = 16.3\%$$

Question:

A class-A emitter follower biased with a constant-current source is shown in **Figure 1**. Study **Figure 1** carefully. The transistor parameters are: $\beta = 190$, $V_{BE} = 0.7 \text{ V}$, and $V_{CE(\text{sat})} = 0.2 \text{ V}$. Neglecting base currents:

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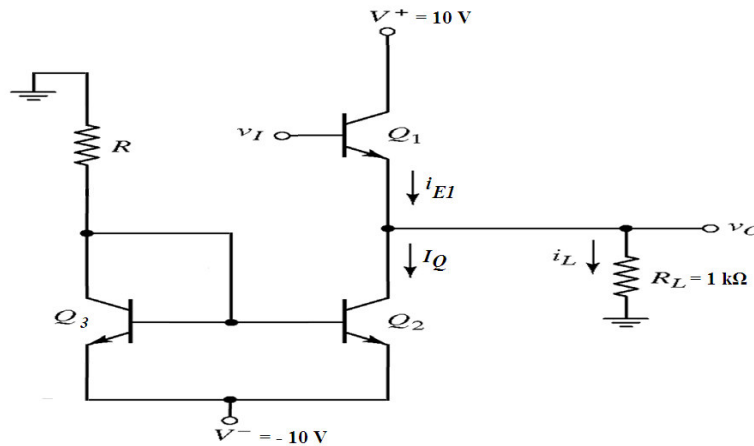


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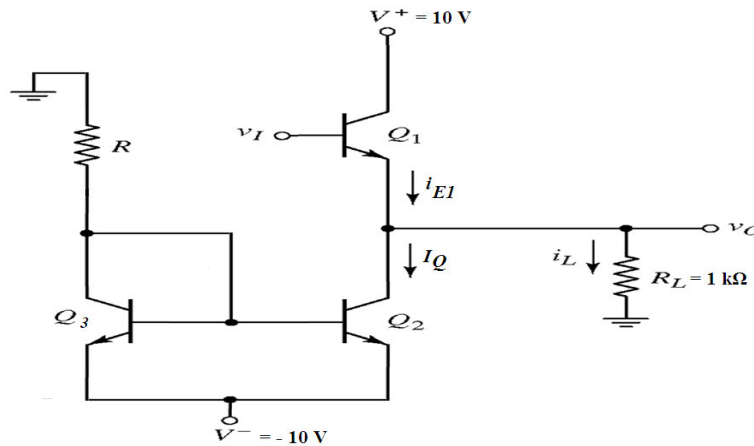


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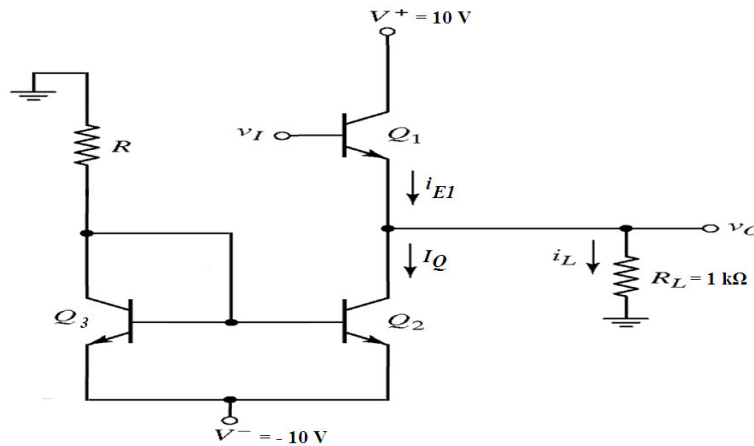


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